	Application No.	Applicant(s)	
Notice of Allowability	10/516,927 Examiner	TEE ET AL. Art Unit	
	LXammer		
	Allan Olsen	1763	
The MAILING DATE of this communication appeals all claims being allowable, PROSECUTION ON THE MERITS IS therewith (or previously mailed), a Notice of Allowance (PTOL-85) NOTICE OF ALLOWABILITY IS NOT A GRANT OF PATENT Roof the Office or upon petition by the applicant. See 37 CFR 1.313	(OR REMAINS) CLOSED in this or other appropriate communical GHTS. This application is subje	application. If not included ation will be mailed in due course.	THIS initiative
1. X This communication is responsive to the after-final amend	ment filed February 01, 2007.		•
2. The allowed claim(s) is/are <u>15-20</u> .			
 Acknowledgment is made of a claim for foreign priority use a) ☐ All b) ☐ Some* c) ☐ None of the: 	nder 35 U.S.C. § 119(a)-(d) or (f)		
 Certified copies of the priority documents have 	e been received.		
2. Certified copies of the priority documents have			
Copies of the certified copies of the priority do	cuments have been received in	this national stage application from	n the
International Bureau (PCT Rule 17.2(a)).			
* Certified copies not received:		•	
Applicant has THREE MONTHS FROM THE "MAILING DATE" noted below. Failure to timely comply will result in ABANDONN THIS THREE-MONTH PERIOD IS NOT EXTENDABLE.		eply complying with the requiremen	nts
4. A SUBSTITUTE OATH OR DECLARATION must be subm INFORMAL PATENT APPLICATION (PTO-152) which giv			OF
5. CORRECTED DRAWINGS (as "replacement sheets") mu	st be submitted.		
(a) ☐ including changes required by the Notice of Draftsper		TO-948) attached	
1) hereto or 2) to Paper No./Mail Date			
(b) including changes required by the attached Examiner Paper No./Mail Date	's Amendment / Comment or in the	ne Office action of	
Identifying indicia such as the application number (see 37 CFR teach sheet. Replacement sheet(s) should be labeled as such in	1.84(c)) should be written on the di the header according to 37 CFR 1.	awings in the front (not the back) o 121(d).	f
 DEPOSIT OF and/or INFORMATION about the deposit attached Examiner's comment regarding REQUIREMENT 	osit of BIOLOGICAL MATERIA FOR THE DEPOSIT OF BIOLO	AL must be submitted. Note the GICAL MATERIAL.	
Attachment(s)			
1. Notice of References Cited (PTO-892)	5. Notice of Inform	• •	
2. Notice of Draftperson's Patent Drawing Review (PTO-948)	6. ⊠ Interview Summ Paper No./Mail		
3. Information Disclosure Statements (PTO/SB/08),	7. X Examiner's Ame		
Paper No./Mail Date 4. Examiner's Comment Regarding Requirement for Deposit	8. 🗌 Examiner's Stat	ement of Reasons for Allowance	
of Biological Material	9.		
	Ala Olan	Allan Olsen Primary Examiner Art Unit: 1763	

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EXAMINER'S AMENDMENT

An examiner's amendment to the record appears below. Should the changes and/or additions be unacceptable to applicant, an amendment may be filed as provided by 37 CFR 1.312. To ensure consideration of such an amendment, it MUST be submitted no later than the payment of the issue fee.

Authorization for this examiner's amendment was given in a telephone interview with Jennifer Taylor on February 14, 2007.

The application has been amended as follows: in each of steps (h), (i), (j) and (k) in each of claims 15, 17 and 19, "second" has been inserted before "masking", as indicated below:

15. A method of ...

- (a) ...
- (g) ...
- (h) following the step of etching away the first layer of doped silicon in step (e) depositing a <u>second</u> masking layer over the second layer of silicon on the side previously in contact with the first layer of silicon,
- (i) patterning the <u>second</u> masking layer to include an area of no masking at one side of a tip,
 - (j) performing a release etch to remove silicon above the cavity not covered by the <u>second</u> masking layer, and
 - (k) removing the <u>second</u> masking layer.

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- 17. A method of ...
 - (a) ...
 - (g) ...
- (h) following the step of etching away the first layer of doped silicon in step (e) depositing a <u>second</u> masking layer over the second layer of silicon on the side previously in contact with the first layer of silicon,
- (i) patterning the <u>second</u> masking layer to include an area of no masking at one side of a tip,
 - (j) performing a release etch to remove silicon above the cavity not covered by the <u>second</u> masking layer, and
- (k) removing the <u>second</u> masking layer, wherein the etch in step (e) is and electrochemical etch.

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19. A method of ...

- (a) ...
- (g) ...
- (h) following the step of etching away the first layer of doped silicon in step (e) depositing a <u>second</u> masking layer over the second layer of silicon on the side previously in contact with the first layer of silicon,
- (i) patterning the <u>second</u> masking layer to include an area of no masking at one side of a tip,
- (j) performing a release etch to remove silicon above the cavity not covered by the <u>second</u> masking layer, and
- (k) removing the <u>second</u> masking layer, wherein the first layer of silicon is p-type doped silicon and the second layer of silicon is n-type doped silicon.

Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Allan Olsen whose telephone number is 571-272-1441. The examiner can normally be reached on M, W and F: 1-5.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Parviz Hassanzadeh can be reached on 571-272-1435. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free). If you would like assistance from a USPTO Customer Service Representative or access to the automated information system, call 800-786-9199 (IN USA OR CANADA) or 571-272-1000.

Allan Olsen Primary Examiner Art Unit 1763

Alan Olsen